74AUP2G58

Low-power dual PCB configurable multiple function gate Rev. 4 — 31 July 2023 Product data sheet

1. General description

The 74AUP2G58 is a dual configurable multiple function gate with Schmitt-trigger inputs. Each gate within the device can be configured as any of the following logic functions AND, OR, NAND, NOR, XOR, inverter and buffer; using the 3-bit input. All inputs can be connected directly to V_{CC} or GND.

This device ensures very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V.

This device is fully specified for partial power down applications using I_{OFF}. The I_{OFF} circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- Low static power consumption; I_{CC} = 0.9 μA (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial power-down mode operation
- ESD protection:
 - HBM: ANSI/ESDA/JEDEC JS-001 class 3A exceeds 5000 V
 - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
- Specified from -40 °C to +85 °C and -40 °C to +125 °C



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3. Ordering information

Table 1. Ordering information

Type number	Package							
	Temperature range	Name	Description	Version				
74AUP2G58DP	-40 °C to +125 °C	TSSOP10	plastic thin shrink small outline package; 10 leads; body width 3 mm	SOT552-1				
74AUP2G58GU	-40 °C to +125 °C	XQFN10	plastic, extremely thin quad flat package; no leads; 10 terminals; body 1.40 × 1.80 × 0.50 mm	SOT1160-1				

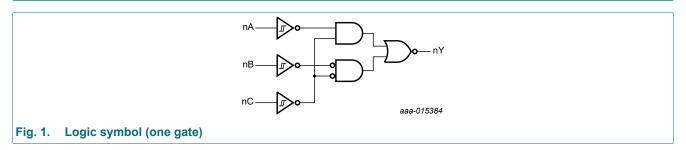
4. Marking

Table 2. Marking

Type number	Marking code[1]
74AUP2G58DP	аК
74AUP2G58GU	аК

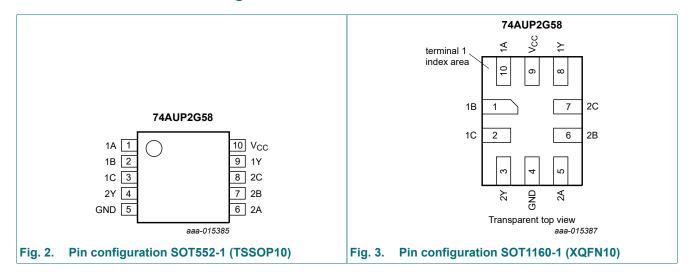
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram



6. Pinning information

6.1. Pinning



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6.2. Pin description

Table 3. Pin description

Symbol	Pin		Description
	SOT552-1 SOT1160-1		
1A, 2A	1, 6	10, 5	data input
1B, 2B	2, 7	1, 6	data input
1C, 2C	3, 8	2, 7	data input
1Y, 2Y	9, 4	8, 3	data output
GND	5	4	ground (0 V)
V _{CC}	10	9	supply voltage

7. Functional description

Table 4. Function table

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level.$

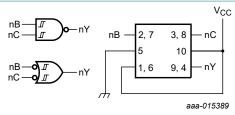
Input			Output
nC	nB	nA	nY
L	L	L	L
L	L	Н	Н
L	Н	L	L
L	Н	Н	Н
Н	L	L	Н
Н	L	Н	Н
Н	Н	L	L
Н	Н	Н	L

7.1. Logic configurations

Table 5. Function selection table

Logic function	Figure
2-input NAND	see Fig. 4
2-input NAND with both inputs inverted	see Fig. 7
2-input AND with inverted input	see Fig. 5 and Fig. 6
2-input NOR with inverted input	see Fig. 5 and Fig. 6
2-input OR	see Fig. 7
2-input OR with both inputs inverted	see Fig. 4
2-input XOR	see Fig. 8
Buffer	see Fig. 9
Inverter	see Fig. 10

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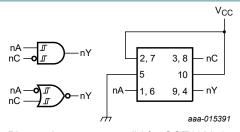


Pin numbers are not valid for SOT1160-1 package

Pin numbers are not valid for SOT1160-1 package

Fig. 4. 2-input NAND gate or 2-input OR with both inputs inverted

Fig. 5. 2-input AND gate with inverted B input or 2-input NOR gate with inverted C input

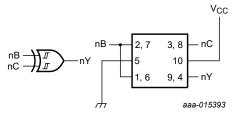


Pin numbers are not valid for SOT1160-1 package

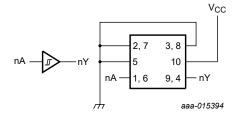
Pin numbers are not valid for SOT1160-1 package

Fig. 6. 2-input AND gate with inverted C input or 2-input NOR gate with inverted A input

Fig. 7. 2-input OR gate or 2-input NAND gate with both inputs inverted



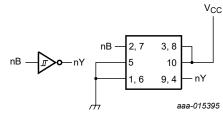
Pin numbers are not valid for SOT1160-1 package



Pin numbers are not valid for SOT1160-1 package

Fig. 8. 2-input XOR gate

Fig. 9. Buffer



Pin numbers are not valid for SOT1160-1 package

Fig. 10. Inverter

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8. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+4.6	V
I _{IK}	input clamping current	V _I < 0 V	-50	-	mA
V _I	input voltage	[1]	-0.5	+4.6	V
lok	output clamping current	V _O < 0 V	-50	-	mA
Vo	output voltage	Active mode and Power-down mode [1]	-0.5	+4.6	V
lo	output current	V _O = 0 V to V _{CC}	-	±20	mA
I _{CC}	supply current		-	50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C to } +125 ^{\circ}\text{C}$ [2]	-	250	mW

The input and output voltage ratings may be exceeded if the input and output current ratings are observed. For SOT552-1 (TSSOP10) packages: P_{tot} derates linearly with 8.3 mW/K above 120 °C.

9. Recommended operating conditions

Table 7. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V _{CC}	V
		Power-down mode; V _{CC} = 0 V	0	3.6	V
T _{amb}	ambient temperature		-40	+125	°C

For SOT1160-1 (XQFN10) package: Ptot derates linearly with 7.1 mW/K above 115 °C.

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10. Static characteristics

Table 8. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 °C					
V _{OH}	HIGH-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I _O = -20 μA; V _{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
V _{OL} I I I I I I I I I		I _O = -1.1 mA; V _{CC} = 1.1 V	0.75 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.11	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.32	-	-	V
		I_{O} = -2.3 mA; V_{CC} = 2.3 V	2.05	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.9	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.72	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.6	-	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I_{O} = 20 μ A; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.31	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	mA; $V_{CC} = 1.4 \text{ V}$ 0.31 mA; $V_{CC} = 1.65 \text{ V}$ 0.31	0.31	V	
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.31	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.44	V
		$I_O = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.31	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.44	V
l _l	input leakage current	V_{I} = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.1	μA
I _{OFF}	power-off leakage current	V_{I} or $V_{O} = 0 \text{ V}$ to 3.6 V; $V_{CC} = 0 \text{ V}$	-	-	±0.2	μA
Δl _{OFF}	additional power-off leakage current	V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V to 0.2 V	-	-	±0.2	μA
I _{CC}	supply current	V_I = GND or V_{CC} ; I_O = 0 A; V_{CC} = 0.8 V to 3.6 V	-	-	0.5	μΑ
ΔI _{CC}	additional supply current	$V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$	-	-	40	μΑ
Cı	input capacitance	V_I = GND or V_{CC} ; V_{CC} = 0 V to 3.6 V	-	1.1	-	pF
Co	output capacitance	V _O = GND; V _{CC} = 0 V	-	1.7	-	pF

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -4	10 °C to +85 °C					
V _{OH}	HIGH-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		$I_{\rm O}$ = -20 μ A; $V_{\rm CC}$ = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.7 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.03	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.30	-	-	V
		I_{O} = -2.3 mA; V_{CC} = 2.3 V	1.97	-	-	V
		I_{O} = -3.1 mA; V_{CC} = 2.3 V	1.85	-	-	V
		I_{O} = -2.7 mA; V_{CC} = 3.0 V	2.67	-	-	V
V _{OL}		I_{O} = -4.0 mA; V_{CC} = 3.0 V	2.55	-	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{T+}$ or V_{T-}				
02		I_{O} = 20 μ A; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.37	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.35	V
		I_{O} = 2.3 mA; V_{CC} = 2.3 V	-	-	0.33	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.45	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.33	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.45	V
l _l	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	±0.5	μA
I _{OFF}	power-off leakage current	V_{I} or $V_{O} = 0 \text{ V to } 3.6 \text{ V; } V_{CC} = 0 \text{ V}$	-	-	±0.5	μA
Δl _{OFF}	additional power-off leakage current	V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V to 0.2 V	-	-	±0.6	μA
I _{CC}	supply current	V_{I} = GND or V_{CC} ; I_{O} = 0 A; V_{CC} = 0.8 V to 3.6 V	-	-	0.9	μA
Δl _{CC}	additional supply current	$V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$	-	-	50	μΑ

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -4	10 °C to +125 °C		1	1	1	
V _{OH}	HIGH-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I_{O} = -20 μ A; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.11	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.6 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	0.93	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.17	-	-	V
		I_{O} = -2.3 mA; V_{CC} = 2.3 V	1.77	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.67	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.40	-	-	V
√ _{OL} I		I_{O} = -4.0 mA; V_{CC} = 3.0 V	2.30	-	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I _O = 20 μA; V _{CC} = 0.8 V to 3.6 V	-	-	0.11	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.33 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.41	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.39	V
		$I_{O} = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.36	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.50	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.36	V
		$I_{O} = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.50	V
l _l	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	±0.75	μΑ
I _{OFF}	power-off leakage current	V_{I} or $V_{O} = 0 \text{ V}$ to 3.6 V; $V_{CC} = 0 \text{ V}$	-	-	±0.75	μΑ
Δl _{OFF}	additional power-off leakage current	V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V to 0.2 V	-	-	±0.75	μA
I _{CC}	supply current	$\begin{split} &I_O = 2.3 \text{ mA; } V_{CC} = 2.3 \text{ V} & - & - \\ &I_O = 3.1 \text{ mA; } V_{CC} = 2.3 \text{ V} & - & - \\ &I_O = 2.7 \text{ mA; } V_{CC} = 3.0 \text{ V} & - & - \\ &I_O = 4.0 \text{ mA; } V_{CC} = 3.0 \text{ V} & - & - \\ &V_I = \text{GND to } 3.6 \text{ V; } V_{CC} = 0 \text{ V to } 3.6 \text{ V} & - & - \\ &V_I \text{ or } V_O = 0 \text{ V to } 3.6 \text{ V; } V_{CC} = 0 \text{ V} & - & - \\ &V_I \text{ or } V_O = 0 \text{ V to } 3.6 \text{ V; } & - & - \\ &V_I \text{ or } V_O = 0 \text{ V to } 3.6 \text{ V; } & - & - \\ &V_I \text{ GND or } V_{CC; I_O} = 0 \text{ A; } & - & - \\ &V_{CC} = 0.8 \text{ V to } 3.6 \text{ V} & - \\ &V_{CC} = 0.8 \text{ V to } 3.6 \text{ V} & - \\ &V_{CC} = 0.8 \text{ V to } 3.6 \text{ V} & - \\ &V_{CC} = 0.8 \text{ V to } 3.6 \text{ V} & - \\ &V_{CC} = 0.8 \text{ V to } 3.6 \text{ V} & - \\ &V_{CC} = 0.8 \text{ V to } 3.6 \text{ V} & - \\ &V_{CC} = 0.8 \text{ V to } 3.6 \text{ V} & - \\ &V_{CC} = 0.8 \text{ V to } 3.6 \text{ V} & - \\ &V_{CC} = 0.8 \text{ V to } 3.6 \text{ V} & - \\ &V_{CC} = 0.8 \text{ V to } 3.6 \text{ V} & - \\ &V_{CC} = 0.8 \text{ V to } 3.6 \text{ V} & - \\ &V_{CC} = 0.8 \text{ V to } 3.6 \text{ V} & - \\ &V_{CC} = 0.8 \text{ V to } 3.6 \text{ V} & - \\ &V_{CC} = 0.8 \text{ V to } 3.6 \text{ V} & - \\ &V_{CC} = 0.8 V t$		1.4	μA	
ΔI _{CC}	additional supply current	$V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$	-	-	75	μA

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11. Dynamic characteristics

Table 9. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit, see Fig. 12.

Symbol Parameter		Conditions	T _{amb} = 25 °C			T _{an}	_{nb} = o +85 °C	T _{ar} -40 °C to	_{nb} = o +125 °C	Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
C _L = 5 pl	F									
t _{pd}	propagation delay	nA, nB and nC to nY; [2] see Fig. 11								
		V _{CC} = 0.8 V	-	22.8	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.8	6.6	12.9	2.6	13.1	2.6	13.3	ns
		V _{CC} = 1.4 V to 1.6 V	2.4	4.8	7.6	2.4	8.3	2.4	8.6	ns
		V _{CC} = 1.65 V to 1.95 V	2.1	4.0	6.3	2.0	6.9	2.0	7.3	ns
		V _{CC} = 2.3 V to 2.7 V	2.0	3.2	4.6	1.8	5.1	1.8	5.4	ns
		V _{CC} = 3.0 V to 3.6 V	1.9	2.9	3.9	1.6	4.2	1.6	4.4	ns
C _L = 10	pF					1				
t _{pd}	propagation delay	nA, nB and nC to nY; [2] see Fig. 11								
		V _{CC} = 0.8 V	-	26.4	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.2	7.4	14.5	3.0	14.9	3.0	15.2	ns
		V _{CC} = 1.4 V to 1.6 V	2.7	5.4	8.7	2.7	9.4	2.7	9.8	ns
		V _{CC} = 1.65 V to 1.95 V	2.5	4.5	7.1	2.3	7.9	2.3	8.3	ns
		V _{CC} = 2.3 V to 2.7 V	2.4	3.8	5.3	2.2	5.9	2.2	6.2	ns
		V _{CC} = 3.0 V to 3.6 V	2.3	3.5	4.6	1.9	4.9	1.9	5.1	ns
C _L = 15	pF					'		l	1	
t _{pd}	propagation delay	nA, nB and nC to nY; [2] see Fig. 11								
		V _{CC} = 0.8 V	-	29.9	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.6	8.3	16.1	3.3	16.7	3.3	17.0	ns
		V _{CC} = 1.4 V to 1.6 V	3.0	5.9	9.7	3.0	10.5	3.0	11.0	ns
		V _{CC} = 1.65 V to 1.95 V	2.8	5.0	7.9	2.5	8.7	2.5	9.2	ns
		V _{CC} = 2.3 V to 2.7 V	2.7	4.2	5.9	2.5	6.6	2.5	6.9	ns
		V _{CC} = 3.0 V to 3.6 V	2.5	3.9	5.2	2.2	5.5	2.2	5.8	ns
C _L = 30	pF									
t _{pd}	propagation delay	nA, nB and nC to nY; [2] see Fig. 11								
		V _{CC} = 0.8 V	-	38.0	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.5	10.5	20.8	4.1	21.9	4.1	24.1	ns
		V _{CC} = 1.4 V to 1.6 V	3.8	7.5	12.2	3.8	13.5	3.8	14.1	ns
		V _{CC} = 1.65 V to 1.95 V	3.4	6.3	10.0	3.1	11.2	3.1	11.9	ns
		V _{CC} = 2.3 V to 2.7 V	3.4	5.3	7.5	3.1	8.4	3.1	8.9	ns
		V _{CC} = 3.0 V to 3.6 V	3.3	5.0	6.6	2.9	7.1	2.9	7.4	ns

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Symbol	Parameter Conditions		T,	_{amb} = 25	°C		nb = 0 +85 °C	T _{an} -40 °C to	_{nb} = 0 +125 °C	Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
C _L = 5 p	F, 10 pF, 15 p	F and 30 pF								
C _{PD}	power dissipation	$ f_i = 1 \text{ MHz}; \qquad \qquad [3] $								
	capacitance	V _{CC} = 0.8 V	-	2.7	-	-	-	-	-	pF
		V _{CC} = 1.1 V to 1.3 V	-	2.8	-	-	-	-	-	pF
		V _{CC} = 1.4 V to 1.6 V	-	3.0	-	-	-	-	-	pF
		V _{CC} = 1.65 V to 1.95 V	-	3.2	-	-	-	-	-	pF
		V _{CC} = 2.3 V to 2.7 V	-	3.8	-	-	-	-	-	pF
		V _{CC} = 3.0 V to 3.6 V	-	4.4	-	-	-	-	-	pF

- All typical values are measured at nominal V_{CC}.
- t_{pd} is the same as t_{PLH} and t_{PHL} . All specified values are the average typical values over all stated loads. [3]
- C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$$
 where:

f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching; $\Sigma (C_L \times V_{CC}^{\ 2} \times f_o) = \text{sum of the outputs}.$

11.1. Waveforms and test circuit

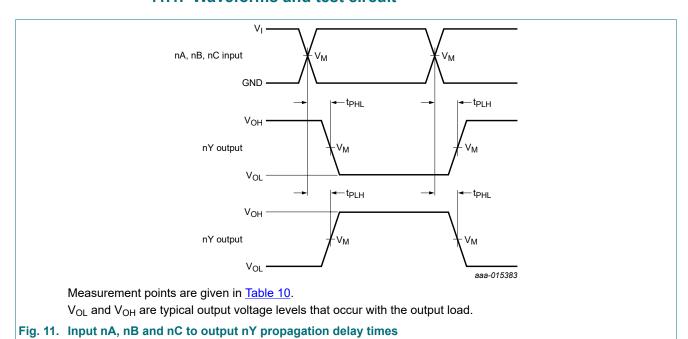
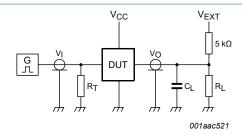


Table 10. Measurement points

Supply voltage	Output	Input		
V _{CC}	V _M	V _M	VI	$t_r = t_f$
0.8 V to 3.6 V	0.5 × V _{CC}	0.5 × V _{CC}	V _{CC}	≤ 3.0 ns

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Test data is given in Table 11.

Definitions for test circuit:

 R_L = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to the output impedance Z_o of the pulse generator.

V_{EXT} = External voltage for measuring switching times.

Fig. 12. Test circuit for measuring switching times

Table 11. Test data

Supply voltage	Load		V _{EXT}			
V _{CC}	CL	R _L [1]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}	
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	2 × V _{CC}	

^[1] For measuring enable and disable times $R_L = 5 \text{ k}\Omega$. For measuring propagation delays, set-up times, hold times and pulse width, $R_L = 1 \text{ M}\Omega$.

12. Transfer characteristics

Table 12. Transfer characteristics

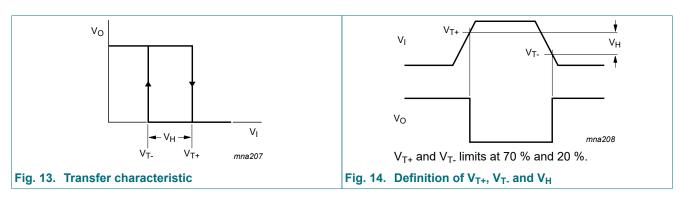
Voltages are referenced to GND (ground = 0 V; for test circuit, see Figure 13.

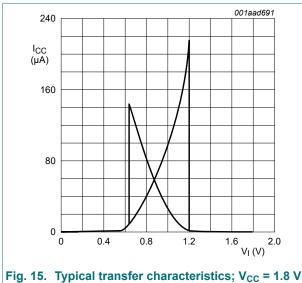
Symbol Parameter		Conditions	Ta	T _{amb} = 25 °C		T _{amb} = -40 °C to +85 °C		T _{amb} = -40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
V_{T+}	positive-	see Fig. 13 and Fig. 14								
	going threshold	V _{CC} = 0.8 V	0.30	-	0.60	0.30	0.60	0.30	0.62	V
	voltage	V _{CC} = 1.1 V	0.53	-	0.90	0.53	0.90	0.53	0.92	V
		V _{CC} = 1.4 V	0.74	-	1.11	0.74	1.11	0.74	1.13	V
		V _{CC} = 1.65 V	0.91	-	1.29	0.91	1.29	0.91	1.31	V
		V _{CC} = 2.3 V	1.37	-	1.77	1.37	1.77	1.37	1.80	V
		V _{CC} = 3.0 V	1.88	-	2.29	1.88	2.29	1.88	2.32	V
V _{T-}	negative-	see Fig. 13 and Fig. 14								
	going threshold	V _{CC} = 0.8 V	0.10	-	0.60	0.10	0.60	0.10	0.60	V
	voltage	V _{CC} = 1.1 V	0.26	-	0.65	0.26	0.65	0.26	0.65	V
		V _{CC} = 1.4 V	0.39	-	0.75	0.39	0.75	0.39	0.75	V
		V _{CC} = 1.65 V	0.47	-	0.84	0.47	0.84	0.47	0.84	V
		V _{CC} = 2.3 V	0.69	-	1.04	0.69	1.04	0.69	1.04	V
		V _{CC} = 3.0 V	0.88	-	1.24	0.88	1.24	0.88	1.24	V

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Symbol	Parameter	Conditions	T _{amb} = 25 °C		T _{am} -40 °C to	_{lb} = o +85 °C	T _{an} -40 °C to	Unit							
			Min	Тур	Max	Min	Max	Min	Max						
V _H r	hysteresis	(V _{T+} - V _{T-}); see <u>Fig. 13</u> , <u>Fig. 14</u> , <u>Fig. 15</u> and <u>Fig. 16</u>													
	voltage	V _{CC} = 0.8 V	0.07	-	0.50	0.07	0.50	0.07	0.50	V					
					V _{CC} = 1.1 V	0.08	-	0.46	0.08	0.46	0.08	0.46	V		
		V _{CC} = 1.4 V	0.18	-	0.56	0.18	0.56	0.18	0.56	V					
							V _{CC} = 1.65 V	0.27	-	0.66	0.27	0.66	0.27	0.66	V
		V _{CC} = 2.3 V	0.53	-	0.92	0.53	0.92	0.53	0.92	V					
		V _{CC} = 3.0 V	0.79	-	1.31	0.79	1.31	0.79	1.31	V					

12.1. Waveforms transfer characteristics





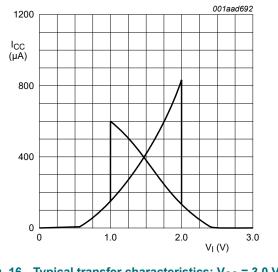


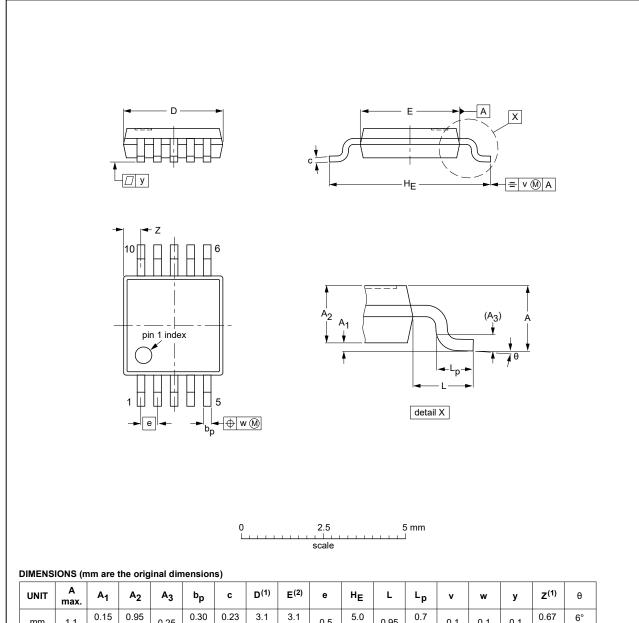
Fig. 16. Typical transfer characteristics; $V_{CC} = 3.0 \text{ V}$

Low-power dual PCB configurable multiple function gate

13. Package outline

TSSOP10: plastic thin shrink small outline package; 10 leads; body width 3 mm

SOT552-1



UN	IIT	A max.	A ₁	A ₂	А3	bp	С	D ⁽¹⁾	E ⁽²⁾	е	HE	L	Lp	v	w	у	Z ⁽¹⁾	θ
mı	m	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.15	0.23 0.15	3.1 2.9	3.1 2.9	0.5	5.0 4.8	0.95	0.7 0.4	0.1	0.1	0.1	0.67 0.34	6° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT552-1						99-07-29 03-02-18

Fig. 17. Package outline SOT552-1 (TSSOP10)

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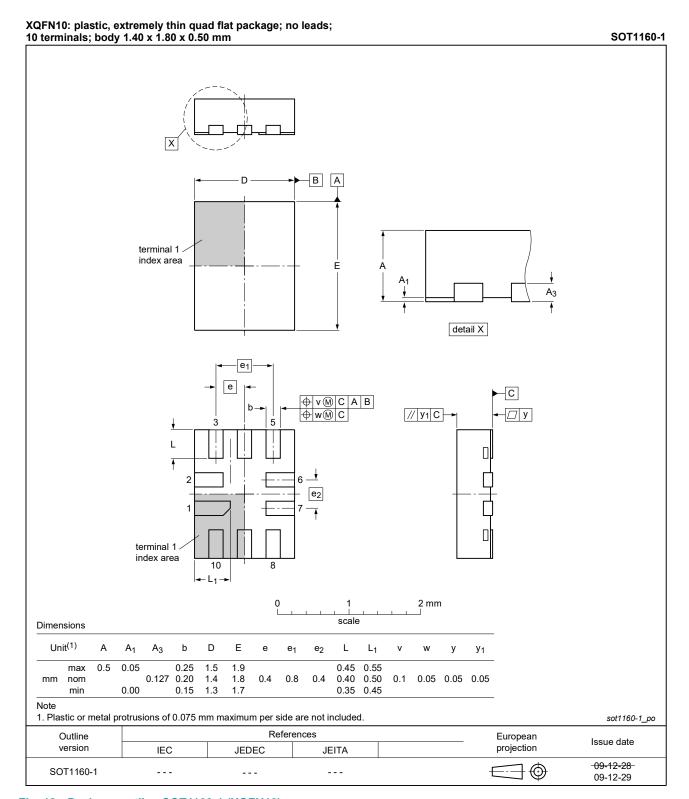


Fig. 18. Package outline SOT1160-1 (XQFN10)

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14. Abbreviations

Table 13. Abbreviations

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
PCB	Printed-Circuit Board

15. Revision history

Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes				
74AUP2G58 v.4	20230731	Product data sheet	-	74AUP2G58 v.3				
Modifications:	Section 2: ESD s	pecification updated according to	the latest JEDEC standa	rd.				
74AUP2G58 v.3	20201207	Product data sheet	-	74AUP2G58 v.2				
Modifications:	 <u>Section 8</u>: Derating values for P_{tot} total power dissipation have been updated. Type number 74AUP2G58GF (SOT1081-1/XSON10) removed. 							
74AUP2G58 v.2	20151202	Product data sheet	-	74AUP2G58 v.1				
Modifications:	 Maximum value temperature range TSSOP10 (74AUP2G58DP) changed from 85 °C to 125 °C. Removed 74AUP2G58GM (SOT1049-3). 							
74AUP2G58 v.1	20141104	Product data sheet	-	-				

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16. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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